

RF power transistor, LdmoST plastic family N-channel enhancement-mode, lateral MOSFETs

Datasheet — production data

Features

- Excellent thermal stability
- Common source configuration
- $P_{OUT} = 2\text{ W}$ with 15dB gain @ 960 MHz / 28 V
- New RF plastic package

Description

The device is a common source N-channel, enhancement-mode lateral field-effect RF power transistor designed for broadband commercial and industrial applications at frequencies up to 1 GHz. The device is designed for high gain and broadband performance operating in common source mode at 28 V. It is ideal for digital cellular BTS applications requiring high linearity. The PowerSO-10 plastic package, designed to offer high reliability, is the first ST JEDEC approved, high power SMD package. It has been specially optimized for RF needs and offers excellent RF performance and ease of assembly.

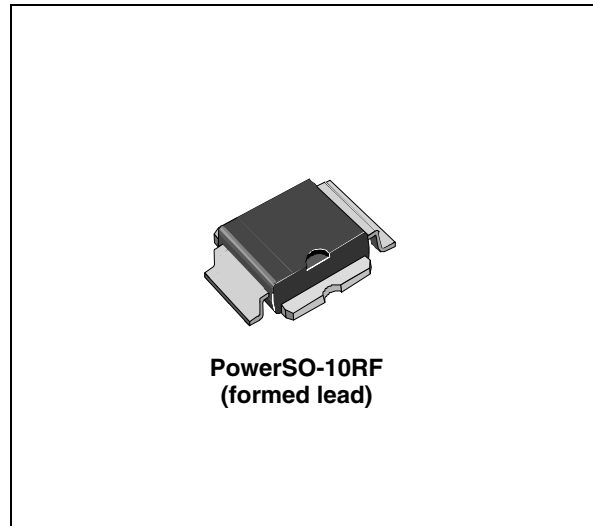


Figure 1. Pin connection

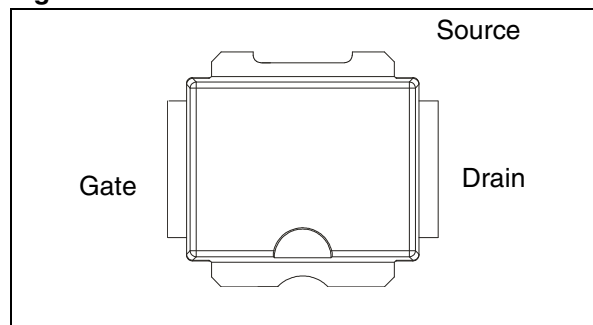


Table 1. Device summary

Order code	Package	Packing
PD57002-E	PowerSO-10RF (formed lead)	Tube

Contents

1	Electrical data	3
1.1	Maximum ratings	3
1.2	Thermal data	3
2	Electrical characteristics	4
2.1	Static	4
2.2	Dynamic	4
2.3	Moisture sensitivity level	4
3	Impedance	5
4	Typical performance	6
5	Common source s-parameter	10
6	Package mechanical data	14
7	Revision history	18

1 Electrical data

1.1 Maximum ratings

Table 2. Absolute maximum ratings ($T_{CASE} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-source voltage	65	V
V_{GS}	Gate-source voltage	± 20	V
I_D	Drain current	0.25	A
P_{DISS}	Power dissipation (@ $T_C = 70^{\circ}C$)	4.75	W
T_J	Max. operating junction temperature	165	$^{\circ}C$
T_{STG}	Storage temperature	-65 to +150	$^{\circ}C$

1.2 Thermal data

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Junction - case thermal resistance	20	$^{\circ}C/W$

2 Electrical characteristics

$T_{CASE} = +25\text{ }^{\circ}\text{C}$

2.1 Static

Table 4. Static

Symbol	Test conditions		Min	Typ	Max	Unit
I_{DSS}	$V_{GS} = 0$	$V_{DS} = 28\text{ V}$			1	μA
I_{GSS}	$V_{GS} = 20\text{ V}$	$V_{DS} = 0$			1	μA
$V_{GS(Q)}$	$V_{DS} = 28\text{ V}$	$I_D = 10\text{ mA}$	2.0		5.0	V
$V_{DS(ON)}$	$V_{GS} = 10\text{ V}$	$I_D = 125\text{ mA}$		0.7	0.9	V
G_{FS}	$V_{DS} = 10\text{ V}$	$I_D = 200\text{ mA}$		--		mho
C_{ISS}	$V_{GS} = 0$	$V_{DS} = 28\text{ V}$		7.1		pF
C_{OSS}	$V_{GS} = 0$	$V_{DS} = 28\text{ V}$		5.8		pF
C_{RSS}	$V_{GS} = 0$	$V_{DS} = 28\text{ V}$		0.1		pF

2.2 Dynamic

Table 5. Dynamic

Symbol	Test conditions		Min	Typ	Max	Unit
P_{1dB}	$V_{DD} = 28\text{ V}$,	$I_{DQ} = 10\text{ mA}$ $f = 960\text{ MHz}$	2			W
G_P	$V_{DD} = 28\text{ V}$,	$I_{DQ} = 10\text{ mA}$, $P_{OUT} = 2\text{ W}$, $f = 960\text{ MHz}$	15			dB
h_D	$V_{DD} = 28\text{ V}$,	$I_{DQ} = 10\text{ mA}$, $P_{OUT} = 2\text{ W}$, $f = 960\text{ MHz}$	45			%
Load mismatch	$V_{DD} = 28\text{ V}$,	$I_{DQ} = 10\text{ mA}$, $P_{OUT} = 2\text{ W}$, $f = 960\text{ MHz}$ All phase angles	10:1			VSWR

2.3 Moisture sensitivity level

Table 6. Moisture sensitivity level

Test methodology	Rating
J-STD-020B	MSL 3

3 Impedance

Figure 2. Current conventions

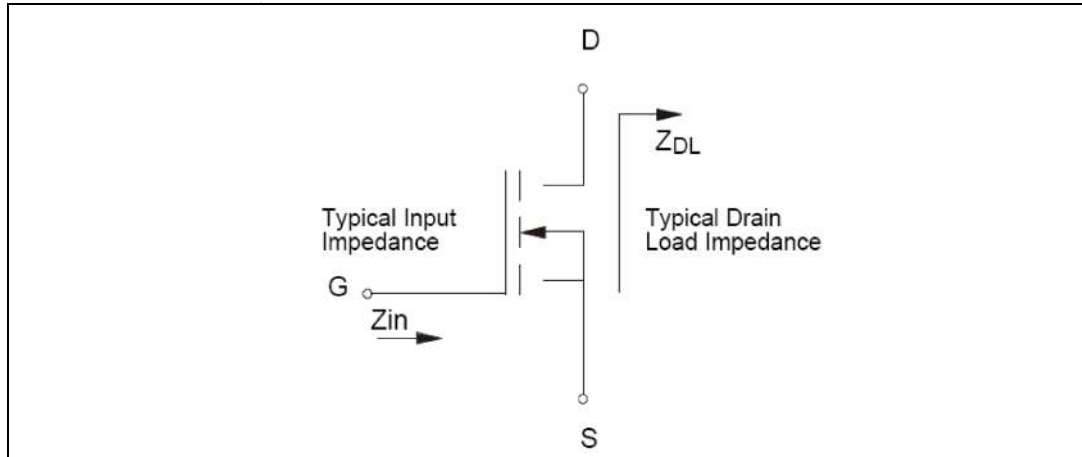


Table 7. Impedance data

Freq. (MHz)	$Z_{IN} (\Omega)$	$Z_{DL} (\Omega)$
925	1.894 - j 13.43	6.445 + j 23.60
945	2.440 - j 12.53	7.245 + j 25.09
960	2.760 - j 12.13	7.715 + j 25.69

4 Typical performance

Figure 3. Capacitance vs supply voltage

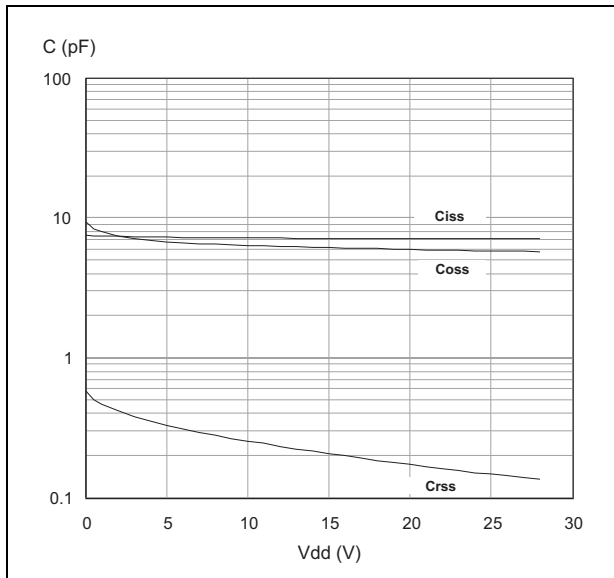


Figure 4. Drain current vs gate source voltage

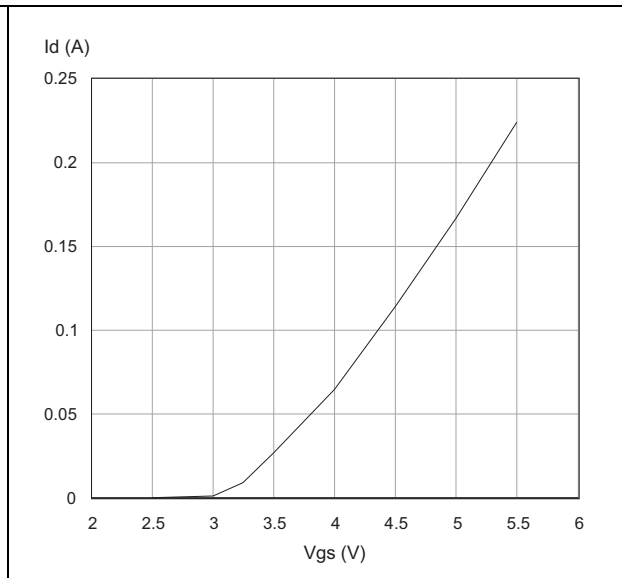


Figure 5. Gate-source voltage vs case temperature

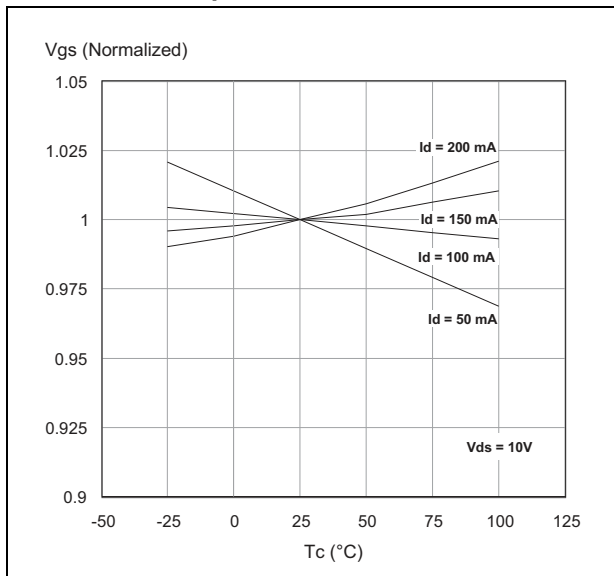


Figure 6. Output power vs input power

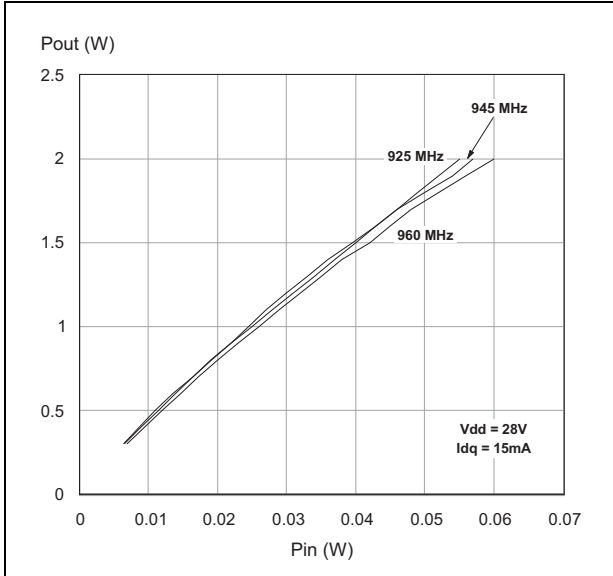


Figure 7. Input return loss vs output power

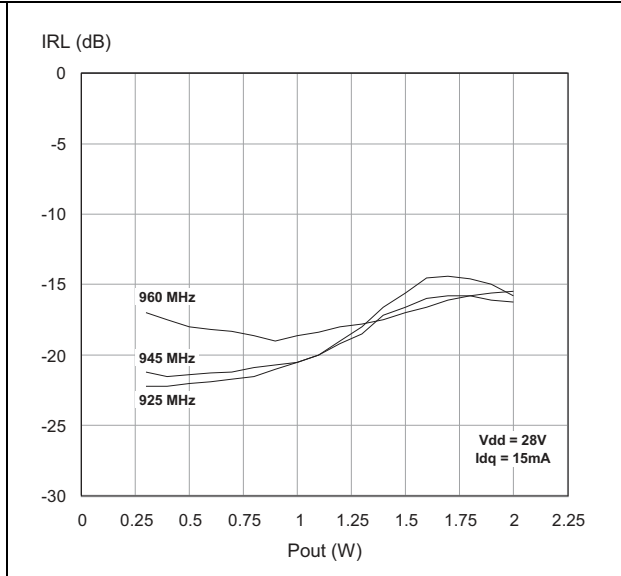


Figure 8. Power gain vs output power

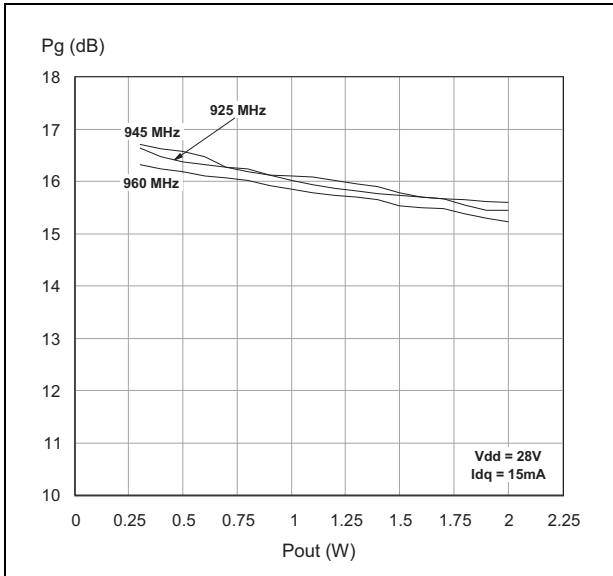


Figure 9. Efficiency vs output power

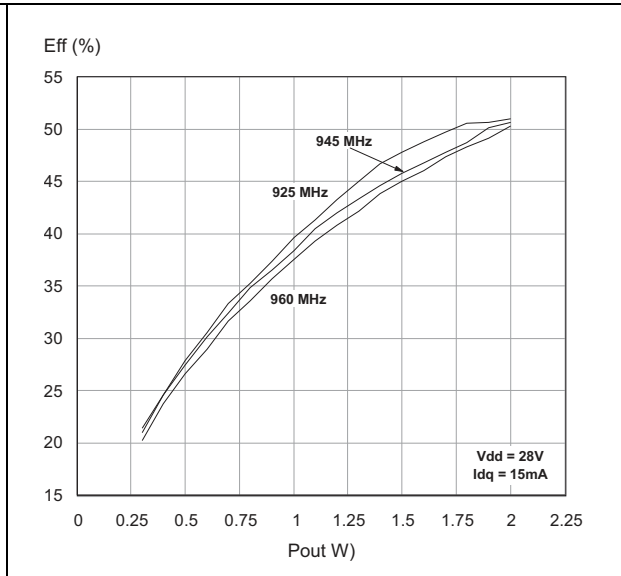


Figure 10. Output power vs drain voltage

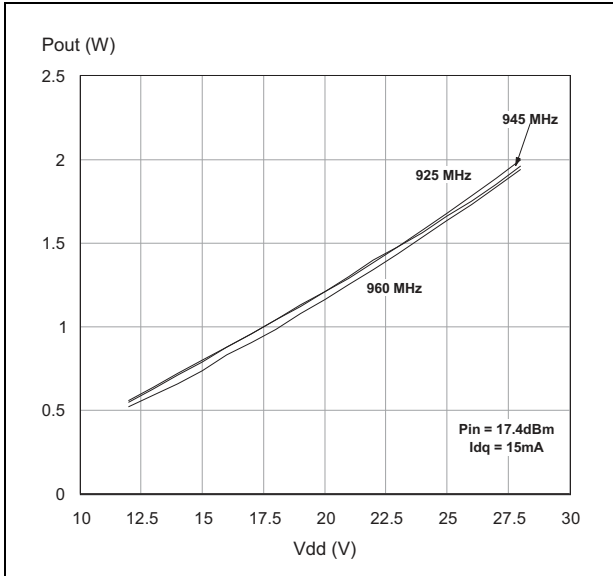


Figure 11. Efficiency vs drain voltage

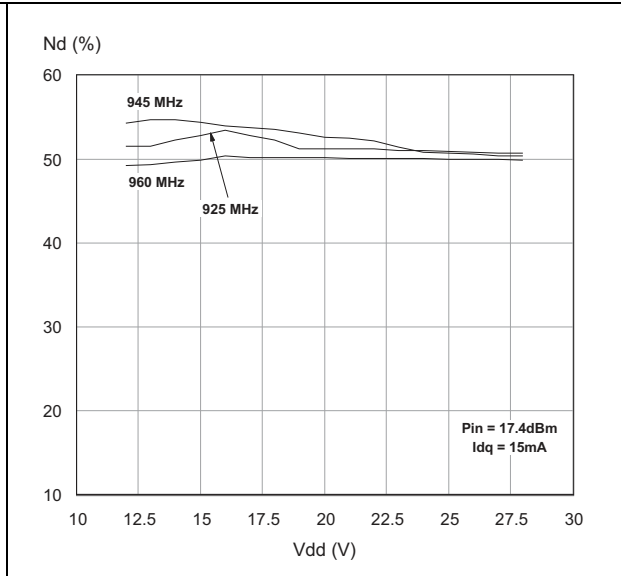


Figure 12. Output power vs drain current

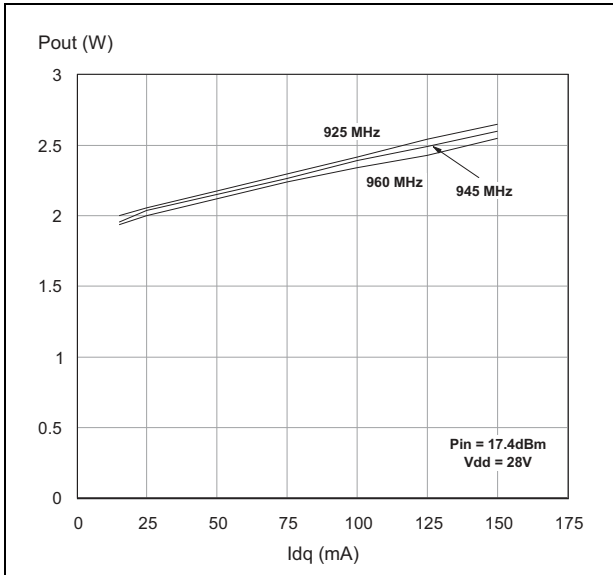


Figure 13. Efficiency vs drain current

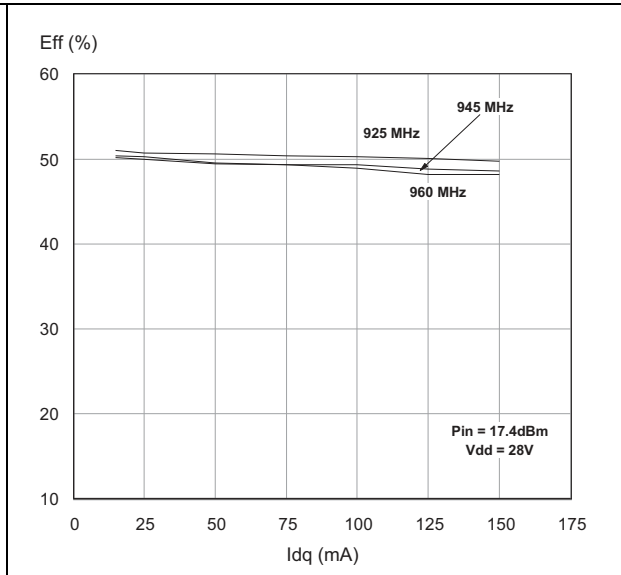
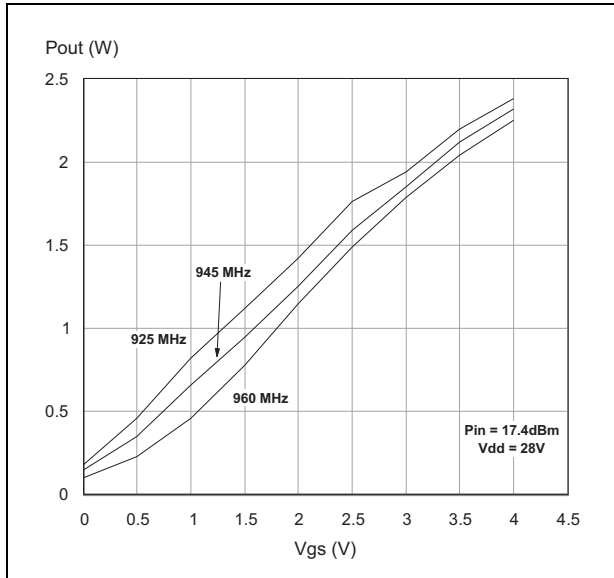


Figure 14. Output power vs gate-source voltage



5 Common source s-parameter

Table 8. S-parameter for PD57002-E ($V_{DS} = 28\text{ V}$ $I_{DS} = 75\text{ mA}$)

Freq (MHz)	$ S_{11} $	$S_{11} < \Phi$	$ S_{21} $	$S_{21} < \Phi$	$ S_{12} $	$S_{12} < \Phi$	$ S_{22} $	$S_{22} < \Phi$
50	0.980	-16	10.01	166	0.006	75	0.963	-12
100	0.972	-31	9.63	153	0.012	64	0.949	-23
150	0.966	-46	9.04	141	0.017	53	0.942	-35
200	0.951	-59	8.46	129	0.020	42	0.918	-45
250	0.944	-70	7.78	119	0.023	32	0.911	-54
300	0.936	-80	7.09	110	0.025	23	0.896	-63
350	0.925	-90	6.50	101	0.026	16	0.885	-70
400	0.926	-98	5.93	93	0.026	8	0.888	-77
450	0.924	-105	5.43	85	0.026	2	0.886	-83
500	0.919	-112	4.96	78	0.027	-2	0.897	-89
550	0.921	-117	4.52	72	0.027	-9	0.894	-95
600	0.915	-122	4.17	66	0.026	-15	0.896	-99
650	0.920	-127	3.84	61	0.026	-20	0.904	-104
700	0.922	-131	3.55	56	0.024	-25	0.914	-108
750	0.921	-135	3.31	51	0.024	-29	0.920	-112
800	0.922	-138	3.07	46	0.023	-33	0.929	-116
850	0.924	-141	2.87	42	0.022	-38	0.937	-119
900	0.922	-145	2.69	38	0.021	-39	0.934	-123
950	0.926	-147	2.52	34	0.020	-43	0.931	-125
1000	0.919	-150	2.38	30	0.019	-45	0.938	-128
1050	0.920	-153	2.24	27	0.018	-49	0.941	-131
1100	0.918	-155	2.13	23	0.018	-51	0.941	-134
1150	0.916	-158	2.02	19	0.017	-56	0.943	-136
1200	0.921	-160	1.92	16	0.016	-60	0.940	-138
1250	0.912	-162	1.84	12	0.015	-62	0.943	-141
1300	0.914	-164	1.76	9	0.014	-70	0.944	-143
1350	0.914	-166	1.68	6	0.013	-71	0.942	-144
1400	0.908	-168	1.61	3	0.013	-75	0.947	-146
1450	0.909	-170	1.54	0	0.012	-88	0.940	-148
1500	0.900	-172	1.45	-3	0.011	-108	0.934	-149

Table 9. S-parameter PD57002-E ($V_{DS} = 28\text{ V}$ $I_{DS} = 150\text{ mA}$)

Freq (MHz)	$ S_{11} $	$S_{11} < \Phi$	$ S_{21} $	$S_{21} < \Phi$	$ S_{12} $	$S_{12} < \Phi$	$ S_{22} $	$S_{22} < \Phi$
50	0.998	-17	10.95	166	0.006	77	0.960	-12
100	0.989	-32	10.50	153	0.011	63	0.946	-24
150	0.975	-47	9.83	140	0.016	52	0.937	-35
200	0.965	-61	9.15	128	0.020	41	0.912	-45
250	0.954	-72	8.40	118	0.022	31	0.904	-54
300	0.943	-82	7.63	108	0.024	22	0.885	-63
350	0.939	-92	6.98	100	0.025	15	0.876	-70
400	0.934	-100	6.35	92	0.025	7	0.880	-77
450	0.931	-107	5.81	84	0.026	2	0.877	-83
500	0.930	-113	5.30	77	0.026	-3	0.885	-89
550	0.927	-119	4.82	71	0.025	-9	0.886	-95
600	0.925	-124	4.45	65	0.025	-15	0.886	-99
650	0.927	-128	4.09	60	0.025	-21	0.896	-104
700	0.926	-133	3.78	55	0.023	-25	0.906	-108
750	0.930	-136	3.52	50	0.022	-29	0.912	-112
800	0.930	-140	3.27	45	0.021	-33	0.923	-115
850	0.931	-143	3.06	41	0.021	-36	0.929	-119
900	0.930	-146	2.87	36	0.200	-40	0.930	-122
950	0.929	-149	2.68	33	0.019	-42	0.928	-125
1000	0.931	-152	2.53	29	0.018	-46	0.933	-128
1050	0.926	-154	2.38	25	0.017	-48	0.932	-130
1100	0.927	-157	2.27	21	0.016	-54	0.935	-133
1150	0.926	-159	2.15	18	0.016	-57	0.938	-136
1200	0.925	-161	2.04	14	0.015	-58	0.940	-138
1250	0.923	-164	1.95	11	0.014	-62	0.941	-140
1300	0.918	-165	1.87	8	0.013	-68	0.939	-142
1350	0.917	-167	1.79	4	0.012	-71	0.936	-144
1400	0.916	-169	1.72	1	0.012	-74	0.939	-146
1450	0.911	-171	1.63	-2	0.011	-89	0.934	-147
1500	0.904	-172	1.54	-5	0.011	-109	0.933	-148

Table 10. S-parameter for PD57002-E ($V_{DS} = 13.5\text{ V}$ $I_{DS} = 75\text{ mA}$)

Freq (MHz)	$ S_{11} $	$S_{11} < \Phi$	$ S_{21} $	$S_{21} < \Phi$	$ S_{12} $	$S_{12} < \Phi$	$ S_{22} $	$S_{22} < \Phi$
50	0.969	-17	10.14	166	0.009	74	0.973	-14
100	0.959	-33	9.72	152	0.017	63	0.954	-27
150	0.949	-48	9.06	139	0.243	50	0.944	-40
200	0.925	-61	8.31	127	0.030	39	0.910	-51
250	0.915	-73	7.57	117	0.033	28	0.901	-61
300	0.906	-83	6.82	108	0.035	20	0.875	-70
350	0.890	-92	6.23	99	0.038	13	0.862	-77
400	0.892	-100	5.65	91	0.039	5	0.866	-85
450	0.888	-106	5.19	84	0.038	-2	0.858	-90
500	0.881	-113	4.72	77	0.039	-6	0.870	-96
550	0.888	-119	4.30	71	0.039	-13	0.873	-102
600	0.882	-123	3.95	65	0.038	-18	0.872	-106
650	0.888	-128	3.62	60	0.038	-24	0.880	-111
700	0.893	-132	3.36	55	0.036	-28	0.890	-116
750	0.890	-135	3.12	51	0.036	-32	0.895	-119
800	0.895	-139	2.92	46	0.034	-36	0.904	-122
850	0.895	-142	2.73	42	0.033	-41	0.911	-126
900	0.893	-145	2.56	37	0.032	-44	0.914	-129
950	0.898	-148	2.40	34	0.030	-47	0.911	-132
1000	0.892	-150	2.25	30	0.030	-50	0.918	-134
1050	0.895	-153	2.13	26	0.029	-54	0.921	-137
1100	0.896	-155	2.20	23	0.028	-58	0.922	-140
1150	0.894	-158	1.92	19	0.027	-60	0.926	-142
1200	0.900	-160	1.83	16	0.026	-64	0.924	-144
1250	0.890	-162	1.74	12	0.025	-67	0.923	-147
1300	0.895	-164	1.67	9	0.024	-72	0.922	-149
1350	0.898	-166	1.58	6	0.023	-73	0.919	-150
1400	0.893	-169	1.51	3	0.023	-79	0.920	-152
1450	0.895	-170	1.43	0	0.021	-86	0.916	-153
1500	0.885	-172	1.35	-1	0.020	-95	0.912	-154

Table 11. S-parameter for PD57002-E ($V_{DS} = 13.5\text{ V}$ $I_{DS} = 150\text{ mA}$)

Freq (MHz)	$ S_{11} $	$S_{11} < \Phi$	$ S_{21} $	$S_{21} < \Phi$	$ S_{12} $	$S_{12} < \Phi$	$ S_{22} $	$S_{22} < \Phi$
50	0.986	-18	11.58	165	0.009	75	0.964	-14
100	0.972	-34	11.04	151	0.017	62	0.940	-28
150	0.955	-50	10.25	138	0.024	49	0.931	-41
200	0.934	-63	9.35	126	0.029	38	0.891	-52
250	0.921	-75	8.48	115	0.032	28	0.883	-62
300	0.909	-85	7.59	106	0.034	19	0.856	-71
350	0.897	-94	6.93	98	0.036	12	0.841	-78
400	0.895	-102	6.27	90	0.037	4	0.847	-86
450	0.892	-109	5.76	83	0.037	-2	0.840	-91
500	0.889	-115	5.23	76	0.037	-7	0.852	-97
550	0.889	-121	4.75	70	0.037	-13	0.852	-103
600	0.886	-125	4.37	65	0.037	-19	0.853	-107
650	0.891	-130	4.00	59	0.036	-23	0.863	-111
700	0.892	-134	3.72	55	0.035	-29	0.871	-116
750	0.895	-137	3.45	50	0.034	-32	0.878	-119
800	0.897	-141	3.23	46	0.033	-36	0.885	-123
850	0.898	-144	3.02	41	0.032	-40	0.897	-126
900	0.898	-147	2.84	37	0.031	-43	0.895	-129
950	0.902	-149	2.66	33	0.029	-47	0.896	-132
1000	0.90058	-152	2.50	29	0.028	-49	0.904	-134
1050	0.897	-155	2.36	26	0.028	-53	0.906	-137
1100	0.900	-157	2.24	22	0.027	-56	0.909	-140
1150	0.898	-159	2.13	19	0.026	-59	0.912	-142
1200	0.901	-162	2.03	15	0.025	-63	0.910	-144
1250	0.898	-164	1.92	12	0.024	-65	0.913	-147
1300	0.897	-166	1.84	8	0.023	-71	0.912	-149
1350	0.897	-167	1.75	5	0.022	-74	0.909	-150
1400	0.896	-170	1.67	2	0.021	-76	0.912	-152
1450	0.895	-171	1.58	-1	0.021	-85	0.905	-153
1500	0.888	-173	1.50	-2	0.020	-97	0.900	-154

6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 12. PowerSO-10RF formed lead (Gull Wing) mechanical data

Dim	mm			Inch		
	Min	Typ	Max	Min	Typ	Max
A1	0	0.05	0.1	0.	0.0019	0.0038
A2	3.4	3.5	3.6	0.134	0.137	0.142
A3	1.2	1.3	1.4	0.046	0.05	0.054
A4	0.15	0.2	0.25	0.005	0.007	0.009
a		0.2			0.007	
b	5.4	5.53	5.65	0.212	0.217	0.221
c	0.23	0.27	0.32	0.008	0.01	0.012
D	9.4	9.5	9.6	0.370	0.374	0.377
D1	7.4	7.5	7.6	0.290	0.295	0.298
E	13.85	14.1	14.35	0.544	0.555	0.565
E1	9.3	9.4	9.5	0.365	0.37	0.375
E2	7.3	7.4	7.5	0.286	0.292	0.294
E3	5.9	6.1	6.3	0.231	0.24	0.247
F		0.5			0.019	
G		1.2			0.047	
L	0.8	1	1.1	0.030	0.039	0.042
R1			0.25			0.01
R2		0.8			0.031	
T	2 deg	5 deg	8 deg	2 deg	5 deg	8 deg
T1		6 deg			6 deg	
T2		10 deg			10 deg	

Note: Resin protrusions not included (max value: 0.15 mm per side).

Figure 15. Package dimensions

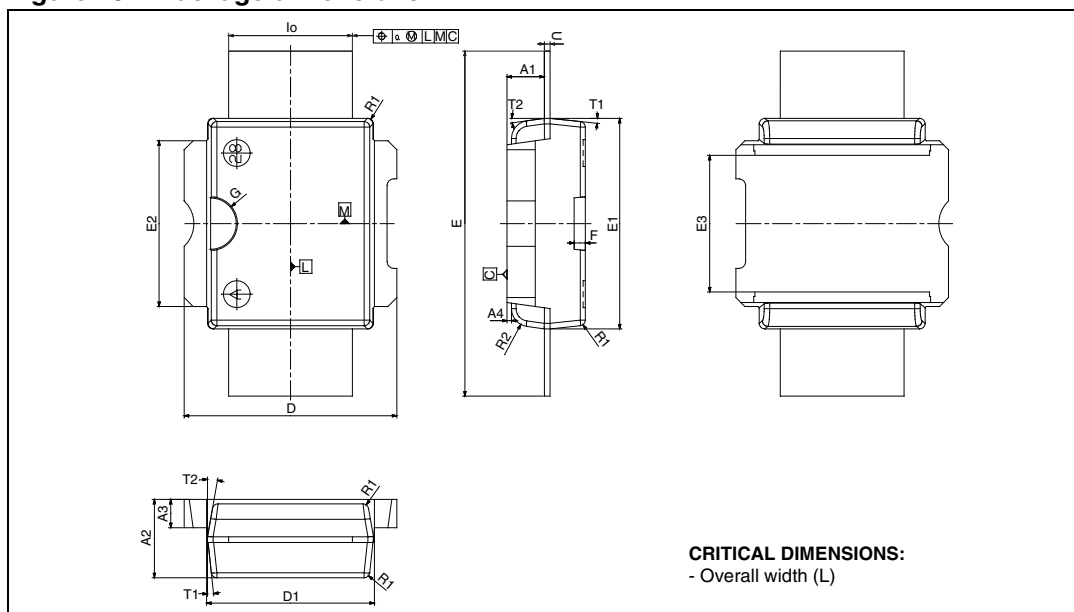
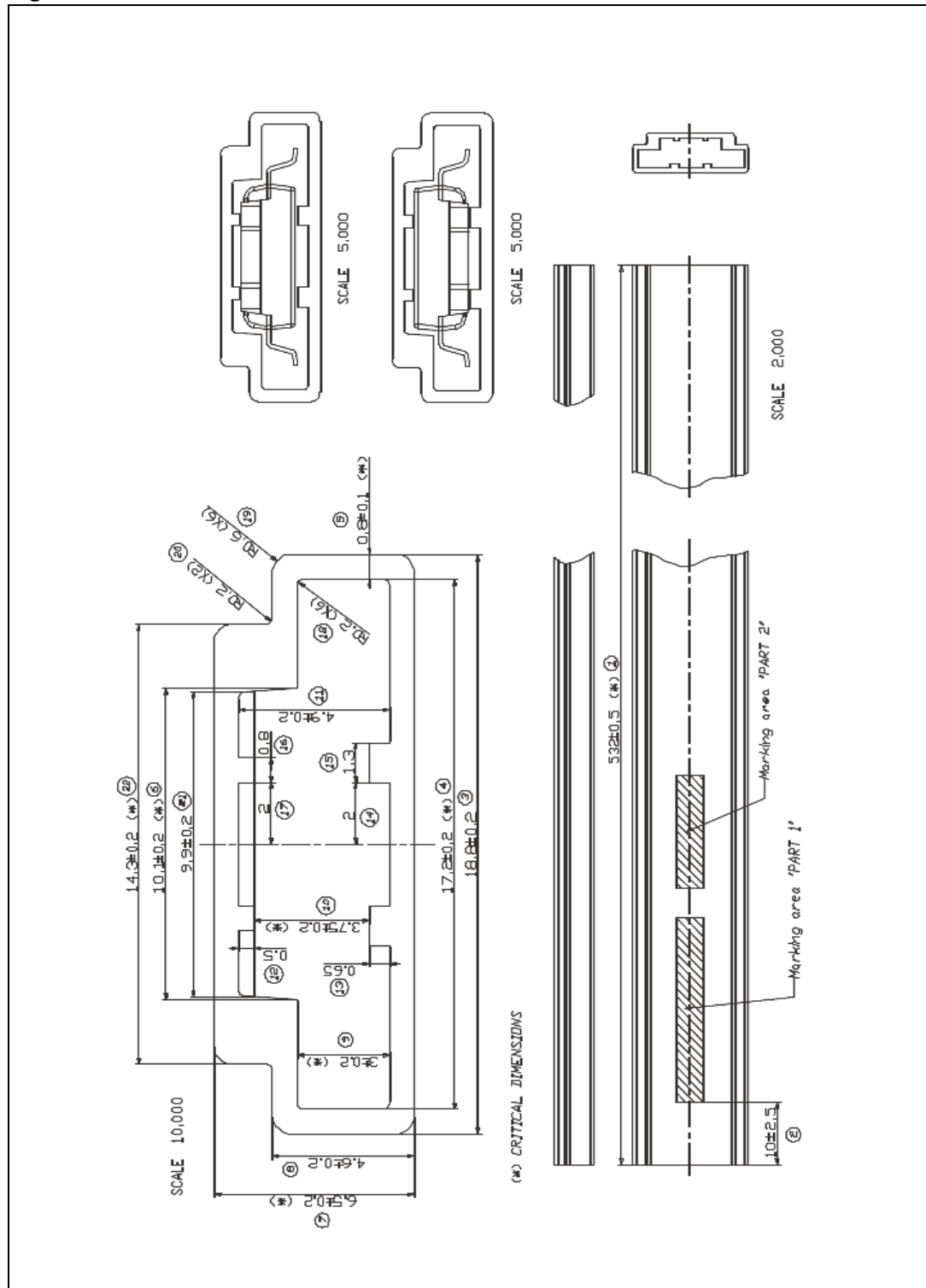


Figure 16. Tube information



7 Revision history

Table 13. Document revision history

Date	Revision	Changes
11-May-2006	1	Initial release.
28-May-2010	2	Added: Table 6: Moisture sensitivity level .
24-Dec-2010	3	Content reworked to improve readability.
31-May-2012	4	Removed: PD57002S-E from Table 1: Device summary . Minor text changes.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY TWO AUTHORIZED ST REPRESENTATIVES, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2012 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

